# BLF578XR; BLF578XRS

# Power LDMOS transistor Rev. 5 — 1 September 2015

**AMPLEON** 

Product data sheet

#### **Product profile** 1.

#### 1.1 General description

A 1400 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 500 MHz band. This product is an enhanced version of the BLF578 using Ampleon's XR process to provide maximum ruggedness capability in the most severe applications without compromising the RF performance.

Table 1. **Application information** 

| Test signal | f     | V <sub>DS</sub> | P <sub>L</sub> | Gp   | η <sub>D</sub> |
|-------------|-------|-----------------|----------------|------|----------------|
|             | (MHz) | (V)             | (W)            | (dB) | (%)            |
| pulsed RF   | 225   | 50              | 1400           | 23.5 | 69             |

#### 1.2 Features and benefits

- Typical pulsed performance at frequency of 225 MHz, a supply voltage of 50 V and an  $I_{Dq}$  of 40 mA, a  $t_p$  of 100  $\mu s$  with  $\delta$  of 20 %:
  - ◆ Output power = 1400 W
  - ◆ Power gain = 23.5 dB
  - ◆ Efficiency = 69 %
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 500 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

## 2. Pinning information

Table 2. Pinning

| IUDIC 2. | ı ııııııg    |                    |                   |
|----------|--------------|--------------------|-------------------|
| Pin      | Description  | Simplified outline | e Graphic symbol  |
| BLF578X  | (R (SOT539A) |                    |                   |
| 1        | drain1       |                    | ,                 |
| 2        | drain2       | 1 2                | <u>.</u> _1       |
| 3        | gate1        | 2, , , , , ,       | 3                 |
| 4        | gate2        | 3 4                | 5                 |
| 5        | source       | [1]                | 4                 |
|          |              |                    | <br>2<br>  sym117 |
|          |              |                    | Oyiii i i         |

| BLF578XRS ( | SOT539B) |     |     |                |
|-------------|----------|-----|-----|----------------|
| 1           | drain1   |     |     |                |
| 2           | drain2   |     | 1 2 | 1<br>. 🔟       |
| 3           | gate1    |     | 5   | , <del> </del> |
| 4           | gate2    |     | 3 4 | 3 - 5          |
| 5           | source   | [1] |     | 2<br>sym117    |

<sup>[1]</sup> Connected to flange.

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |   |         |  |
|-------------|---------|---|---------|--|
|             | Name    | Description   | Version |  |
| BLF578XR    | -       | flanged balanced LDMOST ceramic package;<br>2 mounting holes; 4 leads | SOT539A |  |
| BLF578XRS   | -       | earless flanged balanced LDMOST ceramic package;<br>4 leads           | SOT539B |  |

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter            | Conditions | Min | Max  | Unit |
|------------------|----------------------|------------|-----|------|------|
| $V_{DS}$         | drain-source voltage |            | -   | 110  | V    |
| $V_{GS}$         | gate-source voltage  |            | -6  | +11  | V    |
| T <sub>stg</sub> | storage temperature  |            | -65 | +150 | °C   |
| T <sub>j</sub>   | junction temperature |            | -   | 200  | °C   |

## 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol               | Parameter   | Conditions   | Тур                | Unit |
|----------------------|---|--|--------------------|------|
| R <sub>th(j-c)</sub> | thermal resistance from junction to case          | T <sub>j</sub> = 150 °C                              | [1][2] 0.11        | K/W  |
| $Z_{\text{th(j-c)}}$ | transient thermal impedance from junction to case | $T_j$ = 150 °C; $t_p$ = 100 $\mu$ s; $\delta$ = 20 % | [ <u>3</u> ] 0.033 | K/W  |

- [1]  $T_i$  is the junction temperature.
- [2] Rth(j-c) is measured under RF conditions.
- [3] See Figure 1.

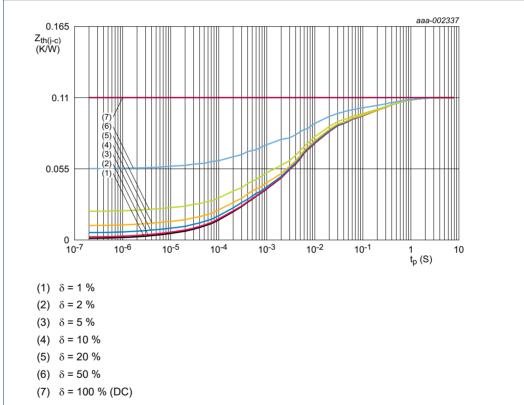


Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

## 6. Characteristics

#### Table 6. DC characteristics

 $T_i = 25$  °C; per section unless otherwise specified.

| Symbol              | Parameter                        | Conditions   | Min  | Тур  | Max  | Unit |
|---------------------|----------------------------------|--|------|------|------|------|
| $V_{(BR)DSS}$       | drain-source breakdown voltage   | $V_{GS} = 0 \text{ V}; I_D = 5.5 \text{ mA}$                       | 110  | -    | -    | V    |
| $V_{GS(th)}$        | gate-source threshold voltage    | $V_{DS}$ = 10 V; $I_{D}$ = 550 mA                                  | 1.25 | 1.7  | 2.25 | V    |
| $V_{GSq}$           | gate-source quiescent voltage    | $V_{DS}$ = 50 V; $I_{D}$ = 20 mA                                   | 8.0  | 1.3  | 1.8  | V    |
| $I_{DSS}$           | drain leakage current            | $V_{GS}$ = 0 V; $V_{DS}$ = 50 V                                    | -    | -    | 2.8  | μΑ   |
| I <sub>DSX</sub>    | drain cut-off current            | $V_{GS} = V_{GS(th)} + 3.75 V;$<br>$V_{DS} = 10 V$                 | -    | 77   | -    | Α    |
| I <sub>GSS</sub>    | gate leakage current             | $V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$                      | -    | -    | 280  | nA   |
| R <sub>DS(on)</sub> | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$<br>$I_D = 19.25 \text{ A}$ | -    | 0.07 | -    | Ω    |

#### Table 7. AC characteristics

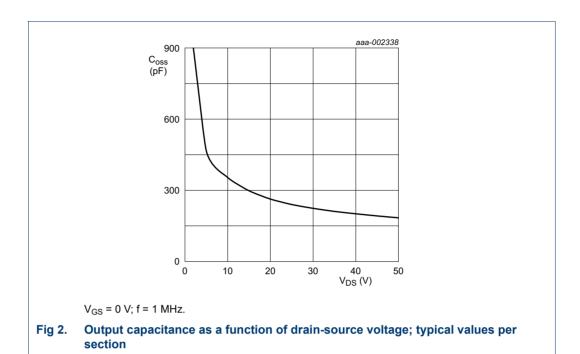
 $T_i = 25$  °C; per section unless otherwise specified.

| Symbol           | Parameter            | Conditions   | Min | Тур | Max | Unit |
|------------------|----------------------|--|-----|-----|-----|------|
| C <sub>rs</sub>  | feedback capacitance | $V_{GS}$ = 0 V; $V_{DS}$ = 50 V; f = 1 MHz                       | -   | 5.5 | -   | pF   |
| C <sub>iss</sub> | input capacitance    | $V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$ | -   | 414 | -   | pF   |
| Coss             | output capacitance   | $V_{GS}$ = 0 V; $V_{DS}$ = 50 V; f = 1 MHz                       | -   | 184 | -   | pF   |

#### Table 8. RF characteristics

Test signal: pulsed RF;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %; f = 225 MHz; RF performance at  $V_{DS}$  = 50 V;  $I_{Dq}$  = 40 mA;  $T_{case}$  = 25  $^{\circ}$ C; unless otherwise specified; in a class-AB production test circuit.

| Symbol     | Parameter         | Conditions              | Min | Тур  | Max | Unit |
|------------|-------------------|-------------------------|-----|------|-----|------|
| Gp         | power gain        | P <sub>L</sub> = 1400 W | 22  | 23.5 | -   | dB   |
| RLin       | input return loss | P <sub>L</sub> = 1400 W | -   | -17  | -13 | dB   |
| $\eta_{D}$ | drain efficiency  | P <sub>L</sub> = 1400 W | 65  | 69   | -   | %    |



## 7. Test information

#### 7.1 Ruggedness in class-AB operation

The BLF578XR and BLF578XRS are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions:  $V_{DS} = 50 \text{ V}$ ;  $I_{Dq} = 40 \text{ mA}$ ;  $P_{L} = 1400 \text{ W}$  pulsed; f = 225 MHz.

## 7.2 Impedance information

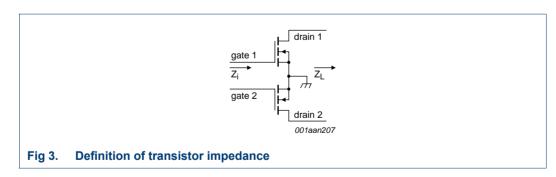
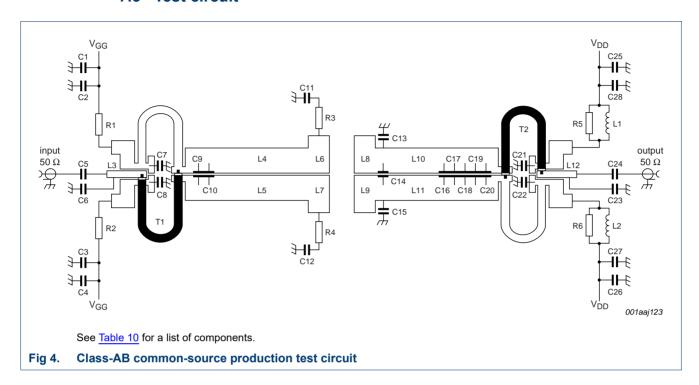


Table 9. Typical push-pull impedance

Simulated  $Z_i$  and  $Z_L$  device impedance; impedance info at  $V_{DS}$  = 50 V and  $P_L$  = 1400 W.

| f     | $Z_i$        | Z <sub>L</sub> |
|-------|--------------|----------------|
| (MHz) | $(\Omega)$   | (Ω)            |
| 225   | 2.36 – j2.78 | 2.45 + j0.86   |

#### 7.3 Test circuit



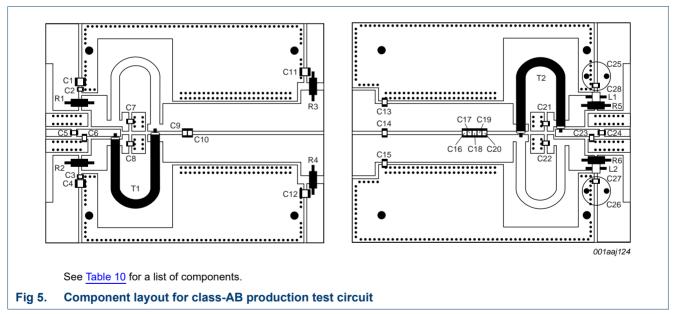


Table 10. List of components

For production test circuit, see Figure 4 and Figure 5.

Printed-Circuit Board (PCB): Rogers 5880;  $\varepsilon_r = 2.2 \text{ F/m}$ ; height = 0.79 mm; Cu (top/bottom metallization); thickness copper plating = 35  $\mu$ m.

| Component            | Description                       | Value                   |     | Remarks                              |
|----------------------|-----------------------------------|-------------------------|-----|--------------------------------------|
| C1, C2, C11, C12     | multilayer ceramic chip capacitor | 4.7 μF                  |     | TDK4532X7R1E475Mt020U                |
| C2, C3, C27, C28     | multilayer ceramic chip capacitor | 100 nF                  |     | Murata X7R 250 V                     |
| C5, C7, C8, C21, C22 | multilayer ceramic chip capacitor | 1 nF                    | [1] |                                      |
| C6                   | multilayer ceramic chip capacitor | 30 pF                   | [1] |                                      |
| C9, C13, C15         | multilayer ceramic chip capacitor | 62 pF                   | [1] |                                      |
| C10                  | multilayer ceramic chip capacitor | 51 pF                   | [1] |                                      |
| C14                  | multilayer ceramic chip capacitor | 36 pF                   | [1] |                                      |
| C16, C17             | multilayer ceramic chip capacitor | 24 pF                   | [1] |                                      |
| C18                  | multilayer ceramic chip capacitor | 30 pF                   | [1] |                                      |
| C19                  | multilayer ceramic chip capacitor | 27 pF                   | [1] |                                      |
| C20                  | multilayer ceramic chip capacitor | 9.1 pF                  | [1] |                                      |
| C23                  | multilayer ceramic chip capacitor | 13 pF                   | [1] |                                      |
| C24                  | multilayer ceramic chip capacitor | 16 pF                   | [1] |                                      |
| C25, C26             | electrolytic capacitor            | 220 μF; 63 V            |     |                                      |
| L1, L2               | 3 turns 1 mm copper wire          | D = 2 mm; length = 3 mm |     |                                      |
| L3, L12              | stripline                         | -                       |     | (L $\times$ W) 15 mm $\times$ 2.4 mm |
| L4, L5, L10, L11     | stripline                         | -                       |     | (L $\times$ W) 47 mm $\times$ 10 mm  |
| L6, L7, L8, L9       | stripline                         | -                       |     | (L $\times$ W) 8 mm $\times$ 15 mm   |
| R1, R2               | metal film resistor               | 2 Ω; 0.6 W              |     |                                      |
| R3, R4               | metal film resistor               | 20 Ω; 0.6 W             |     |                                      |
| R5, R6               | metal film resistor               | 1 Ω; 0.6 W              |     |                                      |
| T1, T2               | semi rigid coax                   | 50 Ω; 58 mm             |     | EZ-141-AL-TP-M17                     |

<sup>[1]</sup> American Technical Ceramics type 100B or capacitor of same quality.

#### 7.4 Graphical data

The following figures are measured in a class-AB production test circuit.

#### 7.4.1 1-Tone CW pulsed

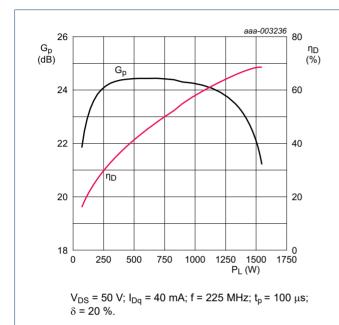
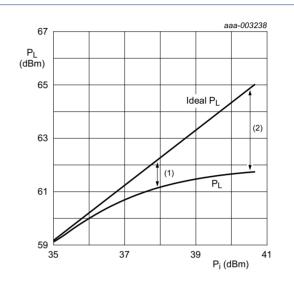


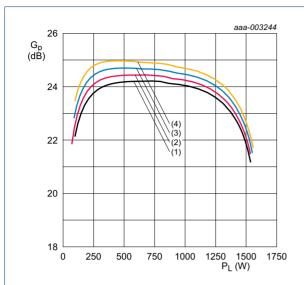
Fig 6. Power gain and drain efficiency as function of output power; typical values



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 40 mA; f = 225 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

- (1)  $P_{L(1dB)} = 61.3 \text{ dBm } (1350 \text{ W})$
- (2)  $P_{L(3dB)} = 61.9 \text{ dBm } (1550 \text{ W})$

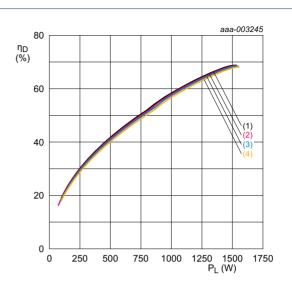
Fig 7. Output power as a function of input power; typical values



 $V_{DS}$  = 50 V; f = 225 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %.

- (1)  $I_{Dq} = 20 \text{ mA}$
- (2)  $I_{Dq} = 40 \text{ mA}$
- (3)  $I_{Dq} = 80 \text{ mA}$
- (4)  $I_{Dq} = 160 \text{ mA}$

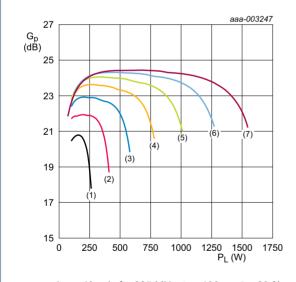
Fig 8. Power gain as a function of output power; typical values



 $V_{DS} = 50 \text{ V}$ ; f = 225 MHz;  $t_p = 100 \text{ } \mu\text{s}$ ;  $\delta = 20 \text{ } \%$ .

- (1)  $I_{Dq} = 20 \text{ mA}$
- (2)  $I_{Dq} = 40 \text{ mA}$
- (3)  $I_{Dq} = 80 \text{ mA}$
- (4)  $I_{Dq} = 160 \text{ mA}$

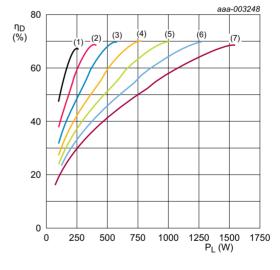
Fig 9. Drain efficiency as a function of output power; typical values



 $I_{Dq}$  = 40 mA; f = 225 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %.

- (1)  $V_{DS} = 20 \text{ V}$
- (2)  $V_{DS} = 25 V$
- (3)  $V_{DS} = 30 \text{ V}$
- (4)  $V_{DS} = 35 V$
- (5)  $V_{DS} = 40 \text{ V}$
- (6)  $V_{DS} = 45 \text{ V}$
- (7)  $V_{DS} = 50 \text{ V}$

Fig 10. Power gain as a function of output power; typical values



 $I_{Dq}$  = 40 mA; f = 225 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %.

- (1)  $V_{DS} = 20 \text{ V}$
- (2)  $V_{DS} = 25 V$
- (3)  $V_{DS} = 30 \text{ V}$
- (4)  $V_{DS} = 35 \text{ V}$
- (5)  $V_{DS} = 40 \text{ V}$
- (6)  $V_{DS} = 45 V$
- (7)  $V_{DS} = 50 \text{ V}$

Fig 11. Drain efficiency as a function of output power; typical values

BLF578XR\_BLF578XRS#5

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## 8. Package outline

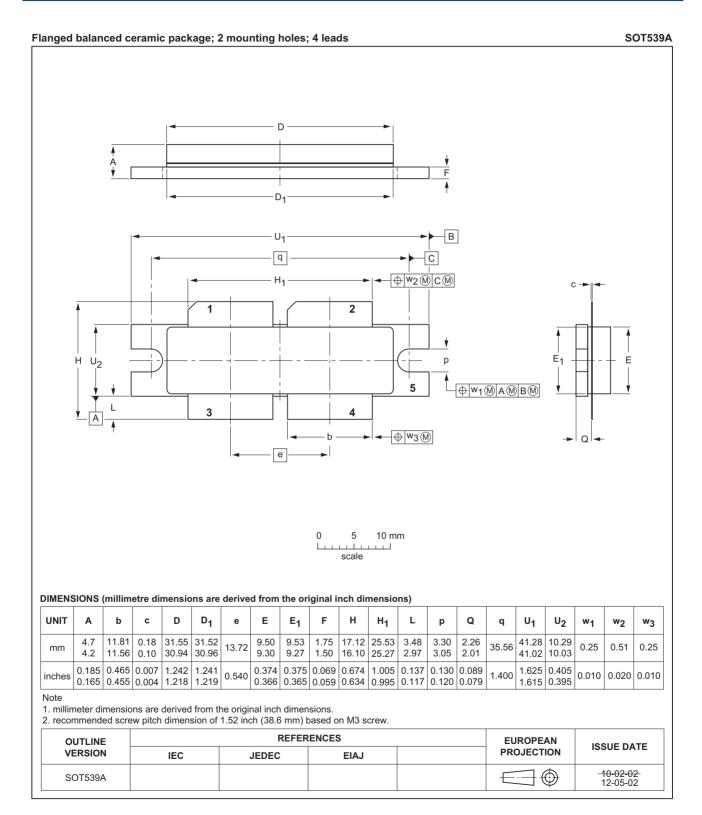


Fig 12. Package outline SOT539A

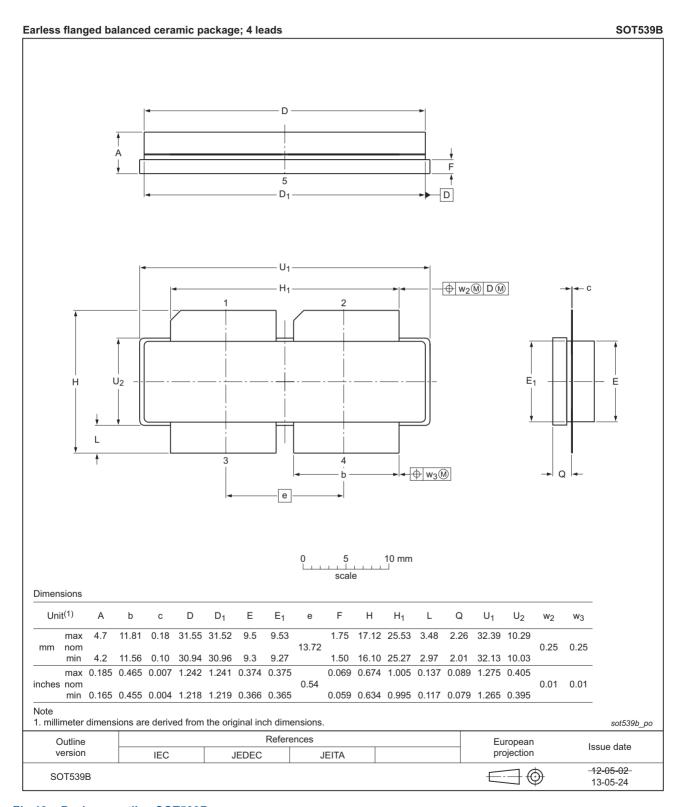


Fig 13. Package outline SOT539B

## 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

## 10. Abbreviations

Table 11. Abbreviations

| Acronym | Description   |
|---------|---|
| CW      | Continuous Wave   |
| ESD     | ElectroStatic Discharge                                 |
| HF      | High Frequency  |
| LDMOS   | Laterally Diffused Metal-Oxide Semiconductor            |
| LDMOST  | Laterally Diffused Metal-Oxide Semiconductor Transistor |
| VSWR    | Voltage Standing-Wave Ratio                             |
| XR      | eXtremely Rugged  |

## 11. Revision history

Table 12. Revision history

| Document ID            | Release date   | Data sheet status      | Change notice | Supersedes             |  |  |
|------------------------|--|------------------------|---------------|------------------------|--|--|
| BLF578XR_BLF578XRS#5   | 20150901   | Product data sheet     | -             | BLF578XR_BLF578XRS v.4 |  |  |
| Modifications:         | <ul> <li>The format of this document has been redesigned to comply with the new identity<br/>guidelines of Ampleon.</li> </ul> |                        |               |                        |  |  |
|                        | <ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>                                   |                        |               |                        |  |  |
| BLF578XR_BLF578XRS v.4 | 20130712   | Product data sheet     | -             | BLF578XR_BLF578XRS v.3 |  |  |
| BLF578XR_BLF578XRS v.3 | 20120625   | Product data sheet     | -             | BLF578XR_BLF578XRS v.2 |  |  |
| BLF578XR_BLF578XRS v.2 | 20120514   | Preliminary data sheet | -             | BLF578XR_BLF578XRS v.1 |  |  |
| BLF578XR_BLF578XRS v.1 | 20120130   | Objective data sheet   | -             | -                      |  |  |

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| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
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- [2] The term 'short data sheet' is explained in section "Definitions"
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**Power LDMOS transistor** 

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## BLF578XR; BLF578XRS

**Power LDMOS transistor** 

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